

FINAL PRODUCT/PROCESS CHANGE NOTIFICATION #16453

Generic Copy

Issue Date: 20 Apr 2010

<u>TITLE</u>: Final Notification for Transfer of PS5 Analog Integrated Circuits Die Manufacturing from ON Semiconductor Piestany (Slovakia) to ON Semiconductor Oudenaarde (Belgium)

PROPOSED FIRST SHIP DATE: 20 Jul 2010

AFFECTED CHANGE CATEGORY(S): ON Semiconductor wafer fab site

FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION: Contact your local ON Semiconductor Sales Office or Peter Lanyon <<u>peter.lanyon@onsemi.com</u>>

SAMPLES: Contact your local ON Semiconductor Sales Office

ADDITIONAL RELIABILITY DATA: Available

Contact your local ON Semiconductor Sales Office or Peter Turlo peter.turlo@onsemi.com

NOTIFICATION TYPE:

Final Product/Process Change Notification (FPCN)

Final change notification sent to customers. FPCNs are issued at least 90 days prior to implementation of the change.

ON Semiconductor will consider this change approved unless specific conditions of acceptance are provided in writing within 30 days of receipt of this notice. To do so, contact <quality@onsemi.com>.

DESCRIPTION AND PURPOSE:

The transfer and qualification of the PowerSense5 process and the associated integrated circuits from the ON Semiconductor Piestany facility (Slovakia) to the ON Semiconductor Oudenaarde facility (Belgium)

The Oudenaarde site is certified according to ISO/TS16949 standards.

The PowerSense5 process is being replicated at Oudenaarde in order to get the same electrical and reliability performances as the Piestany wafer fab.

A full electrical characterization over the temperature range will be performed for each product to check the device functionality and electrical specifications.

Qualification tests are designed to show that the reliability of transferred devices will continue to meet or exceed ON Semiconductor standards.

ON Semiconductor recommends that customers evaluate sample units in each associated application circuit to ensure there are no unexpected electrical incompatibilities.



FINAL PRODUCT/PROCESS CHANGE NOTIFICATION #16453

RELIABILITY DATA SUMMARY:

The qualification vehicles chosen represent the broadest use of possible design library elements and available process modules.

			ONPY2 to Fab2 PS5 Transfer Qualification Summary							
PT 04/	10		Qualification Vehicle 1	Qualification Vehicle 2	Qualified to AEC Q100 Grade 1 (40C to +125C)					
		Device:	NCV7708BDWR2G	NCV7729BPPR2G				-		-
		Description:	Double Hex Driver	8A H-Bridge Driver						
			2.577 x 5.73 mm	3.578 x 5.688 mm						
		Package:	OSPI, 28L SOW f, MSL3/260	ASEkr, 20L PSOP, MSL1/260						
					NCV7708			NCV7729		
Test	#	Reference	Test Conditions	Comments	# Lots	S.S.	Results Fail/Total	# Lots	S.S.	Results Fail/Total
			Test Group A- Accele	rated Environment Stress Tes	s					
		JESD22 A113	Preconditioning: (Test @ R/H) SMD only; Moisture Load and							
PC	A1	J-STD-020	Reflow	PC for AC, TC, THB/HAST	all	all	0/720	all	all	0/720
THB	A2	JESD22 A104	Temp Humidity Blas: (Test @ R/H) 85°C/85% RH, blas, 1008hrs		3	80	0/240	3	80	0/240
AC	A3	JESD22 A102	Autodave: (Test @ R) 121 C/100% RH, 15 psi for 96 hrs		3	80	0/240	3	80	0/240
TC	A4	JESD22 A104	Temperature Cycle: (Test @ R/H) -65*C to+150*C; for 500cyc		3	80	0/240	3	80	0/240
HISL	Aß	JESD22 A103	High Temp Storage Life (Test @ R/H) Ta=150 C for 1008 hrs		3	80	0/240	3	80	0/240
			Test Group B- Accele	rated LifeTime Simulation Tes	s					
HTOL	B1	JESD22 A108	High Temp Operational Life: (Test @ R/H) TJ=150°C for 504hrs.		3	160	0/480	3	160	0/480
ELFR	B2	AEC-Q100-008	Early Life Fall Rate: (Test @ R/H) TA= 125°C for 48hrs		3	800	0/2400	3	800	0/2400
			Test Group C- Pac	kage Assembly integrity Test						
WBS	C1	AEC-Q100-001	Wire Bond Shear Test: Cpk >1.33	In-line data per control plan	30 bonds	5 parts	0/30	30 bonds	5 parts	0/30
WBP	C2	Method 2011	Wire Bond Puli: >5gr. Condition C. 0 fails or Cpk>1.33.		30 bonds	5 parts	0/30	30 bonds	5 parts	0/30
SD		JESD22 B102	Solderability, 8hr steam age, 245°C PbSn solder, >95% cov		3	15	0/45	3	15	0/45
PD	C4	JESD22 B100/8	Physical Dimension	In-line data per control plan	3	10	0/30	3	10	0/30
				Die Fab Reliability Tests						
EM	D1	JESD61	Electromigration	Pass	-	-	-	-	-	-
TDDB	D2	JESD35	Time Dependant Dielectric Breakdown	Pass	-	-	-	-	-	-
HCI	D3	JESD60 & 28	Hot Carrier Injection	Pass	-	-	-	-		-
NBTI	D4	JESD90	Negative Blas Temperature Instability	Pass	-	-	-	-		-
SM	D5	JESD61, 87, 202	Stress Migration	Pass		-	-	-	-	-
			Test Group E	- Electrical Verification						
Test	E1		Pre and Post Stress Electrical Test		All	All		All	All	
HBM			Electrostatic Discharge, Human Body Model/ Machine Model:				Pass 4kV		3/V level	
MM	E2	AEC-Q100-003	(Test @ R/H)		1	model	Pass 200V	1	model	Pass 200V
CDM	E3	AEC-Q100-011	Electrostatic Discharge, Charge Device Model: (Test @ R/H)		1	per spec	Pass 1kV	1	per spec	Pass 1kV
LU	E4	AEC-Q100-004	Latch-up: (Test @ R/H)		1	6	C II, Lev A	1	6	C II, Lev A
ED	Eb	AEC-Q100-009	Electrical Distribution: (Test @ C/ R/ H)		3	30	Cpk > 1.67	2	30	Cpk > 1.67

ON Semiconductor



FINAL PRODUCT/PROCESS CHANGE NOTIFICATION #16453

CHANGED PART IDENTIFICATION:

A letter "B" will be added to the package marking to identify parts from the new wafer fab.

List of affected General Parts:

NCV7703D2G NCV7703D2R2G NCV8518APDG NCV8518APDR2G NCV8518APWG NCV8518APWR2G NCV8612MNR2G NCV8613MNR2G NCV8614MNR2G NCV86601D33R2G NCV86601D50G NCV86601D50R2G NCV86602D33R2G NCV86602D50R2G NCV86603D33R2G NCV86603D50R2G NCV86604D33R2G NCV86604D50R2G NCV8851DBG NCV8851DBR2G NCP4302ADR2G NCP4302BDR2G





FINAL PRODUCT/PROCESS CHANGE NOTIFICATION #16453

List of affected Customer Specific Parts:

SCY994351BDWR2G